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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR 2SK2341

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK2341 is N-channel Power MOS Field Effect Transistor designed for high voltage switching applications.

FEATURES

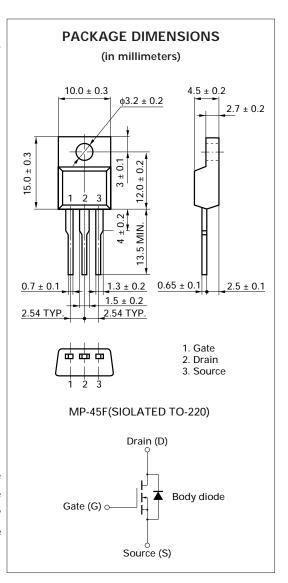
- Low On-state Resistance $R_{DS(on)} = 0.26 \ \Omega \ MAX. \ (V_{GS} = 10 \ V, I_{D} = 6.0 \ A)$
- Low Ciss Ciss = 1090 pF TYP.
- High Avalanche Capability Ratings

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C)

Drain to Source Voltage	VDSS	250	V
Gate to Source Voltage	Vgss	±30	V
Drain Current (DC)	D (DC)	±11	Α
Drain Current (pulse)	ID (pulse)*	± 44	Α
Total Power Dissipation (Tc = 25 °C)	P _{T1}	35	W
Total Power Dissipation (Ta = 25 °C)	P_{T2}	2.0	W
Storage Temperature	T _{stg} -55	to +150	°C
Channel Temperature	Tch	150	°C
Single Avalanche Current	las**	11	Α
Single Avalanche Energy	Eas**	320	mJ

^{*}PW \leq 10 μ s, Duty Cycle \leq 1 %

The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device is actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.



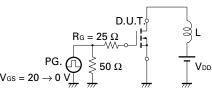
^{**}Starting Tch = 25 °C, RG = 25 Ω , VGS = 20 V ightarrow 0

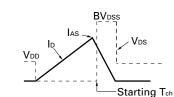


ELECTRICAL CHARACTERISTICS (TA = 25 °C)

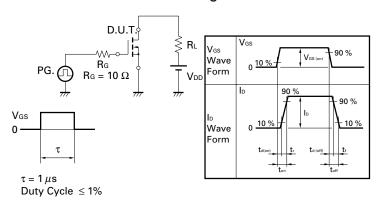
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-state Resistance	RDS(on)		0.21	0.26	Ω	Vgs = 10 V, ID = 6 A
Gate to Source Cutoff Voltage	V _{GS(off)}	2.0		4.0	V	V _{DS} = 10 V, I _D = 1 mA
Forward Transfer Admittance	yfs	3.0			S	V _{DS} = 10 V, I _D = 6 A
Drain Leakage Current	IDSS			100	μΑ	V _{DS} = 250V, V _{GS} = 0
Gate to Source Leakage Current	Igss			±100	nA	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Input Capacitance	Ciss		1090		pF	V _{DS} = 10 V
Output Capacitance	Coss		420		pF	Vgs = 0
Reverse Transfer Capacitance	Crss		80		pF	f = 1 MHz
Turn-On Delay Time	td(on)		20		ns	Vgs = 10 V
Rise Time	tr		20		ns	V _{DD} = 150 V
Turn-Off Delay Time	td(off)		50		ns	$I_D = 6 A$, $R_G = 10 \Omega$
Fall Time	t f		15		ns	R _L = 25 Ω
Total Gate Charge	Q _G		33		nC	Vgs = 10 V
Gate to Source Charge	Qgs		6.0		nC	ID = 11 A
Gate to Drain Charge	Q _{GD}		13		nC	V _{DD} = 200 V
Diode Forward Voltage	V _{F(S-D)}		1.0		V	IF = 11 A, VGS = 0
Reverse Recovery Time	trr		220		ns	1F = 11 A
Reverse Recovery Charge	Qrr		1.0		μC	di/dt = 50 A/μs

Test Circuit 1: Avalanche Capability

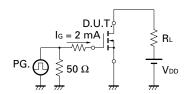




Test Circuit 2: Switching Time



Test Circuit 3: Gate Charge

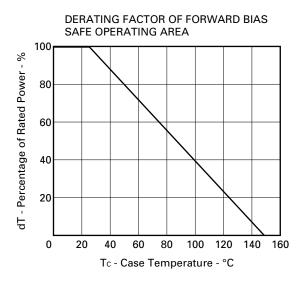


The application circuits and their parameters are for references only and are not intended for use in actual design-in's.

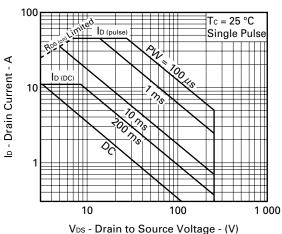
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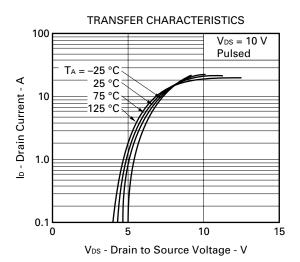


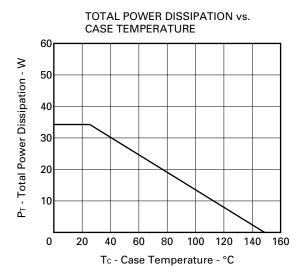
TYPICAL CHARACTERISTICS (TA = 25 °C)

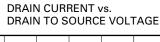


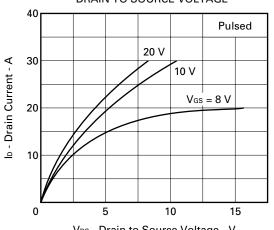
FORWARD BIAS SAFE OPRATING AREA



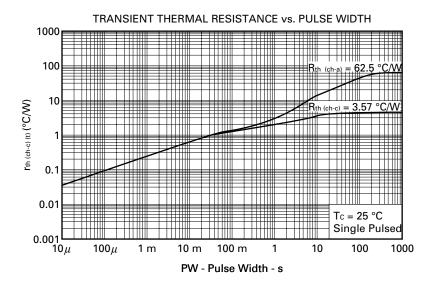




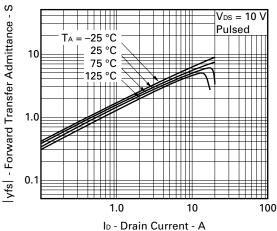


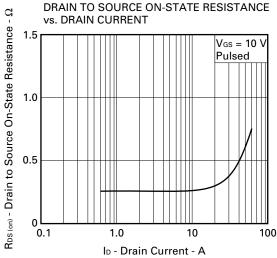


VDS - Drain to Source Voltage - V

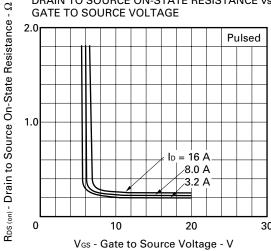




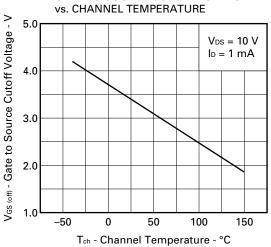




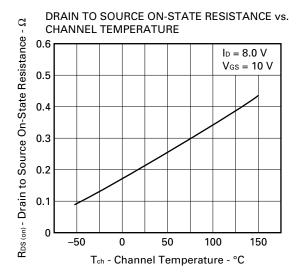
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

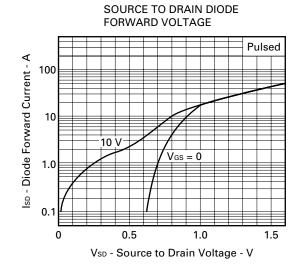


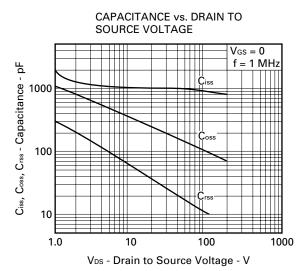
GATE TO SOURCE CUTOFF VOLTAGE

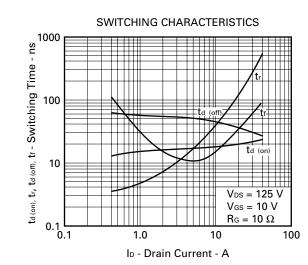


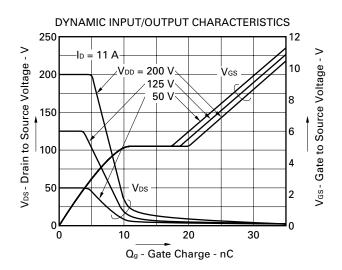


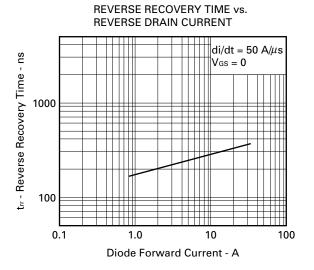






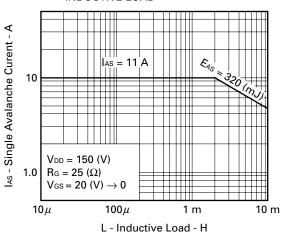




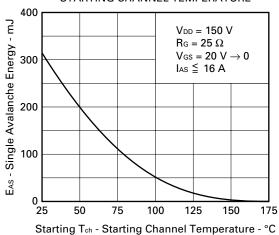




SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



SINGLE AVALANCHE ENERGY vs. STARTING CHANNEL TEMPERATURE





REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134
Power MOS FET features and application switching power supply.	TEA-1034
Application circuits using Power MOS FET.	TEA-1035
Safe operating area of Power MOS FET.	TEA-1037

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